Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RJK0328DPB

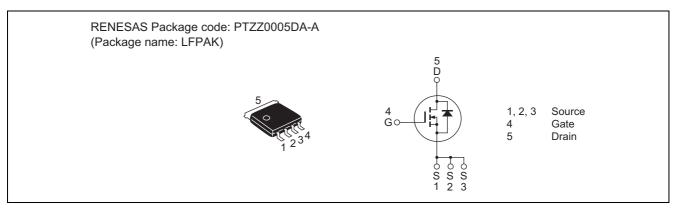
Silicon N Channel Power MOS FET Power Switching

REJ03G1637-0400 Rev.4.00 Apr 10, 2008

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 - $R_{DS(on)} = 1.6 \text{ m}\Omega \text{ typ.} (at V_{GS} = 10 \text{ V})$
- Pb-free

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	Ι _D	60	А
Drain peak current	Note1 I _{D(pulse)}	240	А
Body-drain diode reverse drain current	I _{DR}	60	А
Avalanche current	I _{AP} Note 2	30	А
Avalanche energy	E _{AR} Note 2	90	mJ
Channel dissipation	Pch Note3	65	W
Channel to Case Thermal Resistance	θch-C	1.93	°C/W
Channel temperature	Tch	150	۵°
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \leq 10 \ \mu s, \ duty \ cycle \leq 1\%$

2. Value at Tch = 25°C, Rg \geq 50 Ω

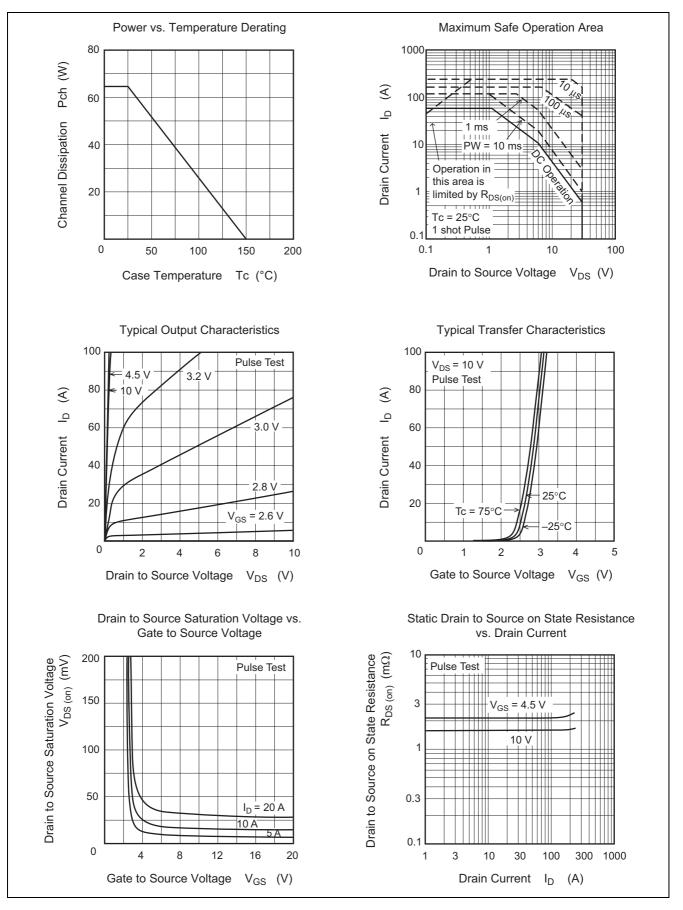
3. Tc = 25°C

Electrical Characteristics

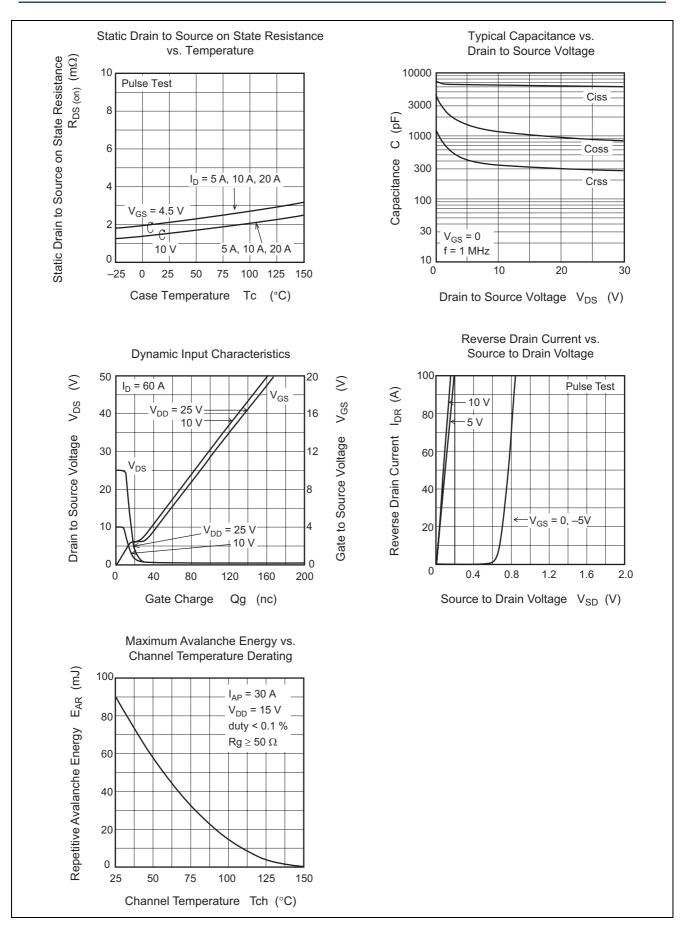
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μΑ	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	—	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	1.6	2.1	mΩ	$I_D = 30 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R _{DS(on)}	_	2.1	2.9	mΩ	$I_D = 30 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note4}$
Forward transfer admittance	y _{fs}	_	100	—	S	$I_D = 30 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	6380	—	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance	Coss		1150	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	—	330	—	pF	
Gate Resistance	Rg	—	0.7	—	Ω	
Total gate charge	Qg	—	42	—	nC	$V_{DD} = 10 \text{ V}, \text{ V}_{GS} = 4.5 \text{ V},$ $I_D = 60 \text{ A}$
Gate to source charge	Qgs	—	15	—	nC	
Gate to drain charge	Qgd	_	8.8	_	nC	
Turn-on delay time	t _{d(on)}	—	9.4	—	ns	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A},$
Rise time	tr	—	4.3	—	ns	$\label{eq:DD} \begin{split} V_{\text{DD}} &\cong 10 \text{ V}, \text{R}_{\text{L}} = 0.33 \Omega, \\ \text{Rg} &= 4.7 \Omega \end{split}$
Turn-off delay time	t _{d(off)}	—	61.5	—	ns	
Fall time	t _f	—	7.3	—	ns	
Body-drain diode forward voltage	V_{DF}	—	0.78	1.02	V	$I_F = 60 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body–drain diode reverse recovery time	t _{rr}	—	42	—	ns	$I_F = 60 \text{ A}, V_{GS} = 0$ $di_F/ dt = 100 \text{ A}/ \mu s$
Body–drain diode reverse recovery charge	Qrr	—	46	—	nC	

Notes: 4. Pulse test

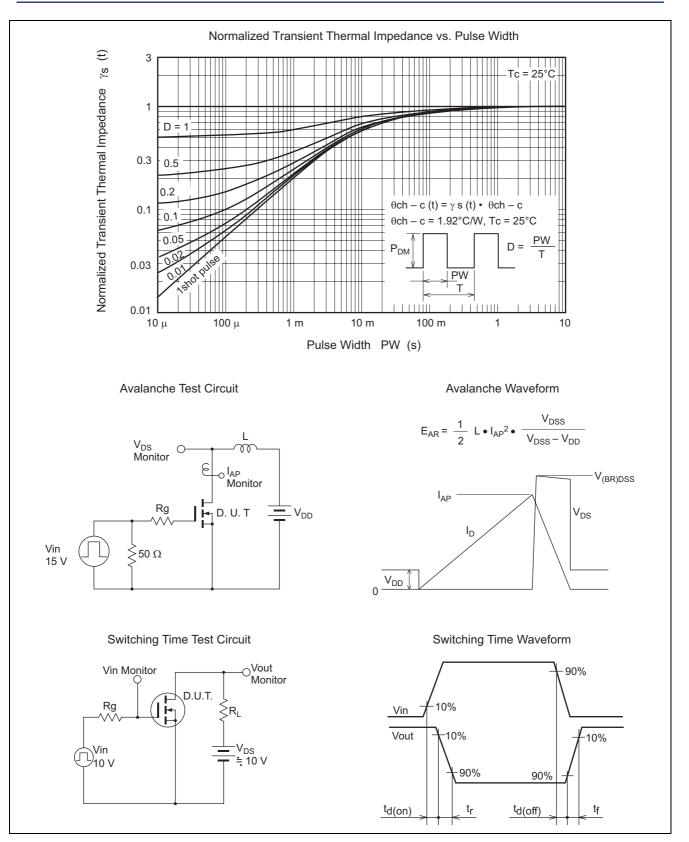
Main Characteristics



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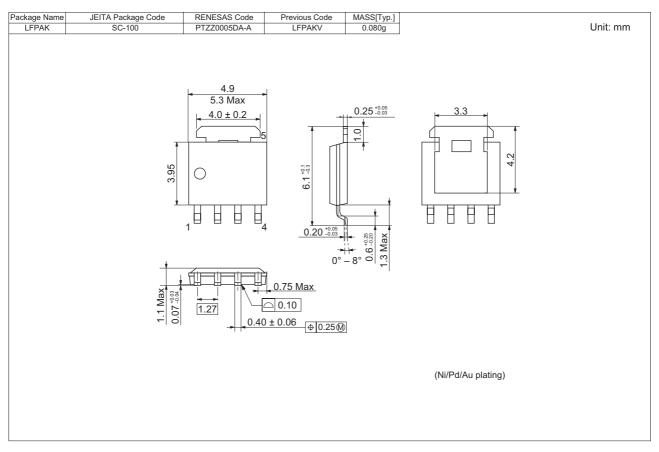


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Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK0328DPB-00-J0	2500 pcs	Taping

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